Surface enhanced Raman scattering of Ag or Au nanoparticle-decorated reduced graphene oxide for detection of aromatic molecules†

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We report a method for fabrication of an efficient surface enhanced Raman scattering (SERS) substrate by combination of metallic nanostructures and graphene, which shows dramatic Raman enhancement and efficient adsorption of aromatic molecules. As an example, the fabricated Ag or Au nanoparticle (NP)-decorated reduced graphene oxide (rGO) on Si substrate is used as an efficient SERS substrate to detect the adsorbed aromatic molecules with a low detection limit at nM level. Systematic studies on the effects of NP size and substrate morphology on Raman enhancement are presented. This method might be useful for the future application in detection of biomolecules, such as DNA and proteins.

Introduction

In the past decades, surface enhanced Raman scattering (SERS) has received much attention in the fields of physics, chemistry, biology, and biomedicine.1–5 Till now, many metallic nanostructures, such as dimers, triangles, nanorods, nanogaps, nanoshells, nanorings, nanocrescents, nanostars and nanoflowers,6–11 have been proven to be SERS active due to the introduction of Raman hot spots. Various SERS substrates have been fabricated by using e-beam lithography, colloidal lithography, nanoimprint lithography, and templated assembly of nanoparticles (NPs).5,12–21 However, due to the less efficient adsorption of some molecules, e.g., non-thiolated aromatic organic molecules, onto the plasmonic metals,6 it is still a challenge to fabricate a SERS substrate for detection of these non-thiolated molecules.13

Graphene, an atomic single-layer of graphite, has been intensively studied in the past years because of its unique electronic, optical, thermal and mechanical properties15–21 and potential applications in the fields of sensing, electric devices, and biology.18,22–24 Among these applications, it has been reported that the mechanically cleaved graphene can serve as a SERS substrate for detection of aromatic molecules with an enhancement factor (EF) of 2–17,25 since graphene shows efficient adsorption towards many molecules, especially the aromatic molecules. A chemical enhancement mechanism was proposed since the surface plasma of graphene is in the terahertz range26 rather than in the visible range. Although the mechanically cleaved graphene can enhance the Raman signals of adsorbed molecules, the EF is too small and the yield of graphene is very low, limiting such method for practical applications.

Compared to the mechanically cleaved graphene, the reduced graphene oxide (rGO), obtained by reduction of graphene oxide (GO),28,36,37 can be produced in high yield, giving a better chance in practical applications. Although graphene with much fewer defects can be obtained using chemical vapour deposition (CVD) method,38–40 it is normally formed on the metal substrate and has to be transferred onto another substrate with complicated processes.

Recently, the Raman property of NP-coated graphene or rGO was investigated.41–44 However, those reports mainly focused on synthesis of the composite of NP-graphene or rGO, and the enhanced Raman signal of graphene or rGO. Till now, seldom work has been carried out to study the Raman signal of adsorbed molecules on NP-decorated rGO.

Herein, we develop a simple and convenient method to fabricate Ag or Au NP-decorated single-layer rGO film on Si surface. The as-fabricated SERS substrates show dramatic Raman enhancement and efficient adsorption of rhodamine 6G (R6G), methyl violet (MV), rhodamine B (RB) and methylene blue (MB) owing to Ag or Au NPs and rGO, respectively. Subsequently, the SERS substrates are used to detect R6G, MV, RB and MB. It was found that the detection limit could be as low as nM.

Results and discussion

GO sheets were firstly assembled onto a freshly cleaned Si substrate using a Langmuir–Blodgett (LB) method46,47 to form single-layer GO film. Note that a few double layers might be also obtained, which arose from the irreversible stacking of the size mismatched GO sheets due to face-to-face interactions during the LB process.46 After GO was reduced by hydrazine,28,36,37 the
formed rGO-covered Si was decorated with a layer of Ag NPs by simply immersing the wafer into a mixed solution of HF and AgNO₃. At the reaction time of 10 s, Ag NPs can be easily deposited onto both rGO sheets and exposed Si region (Fig. 1A). The size and density of Ag NPs formed on rGO sheets are smaller and lower than those on the exposed Si region, respectively (Fig. 1B, C). It indicates that Ag⁺ was reduced and Ag NPs formed on Si surface, which is consistent with the previous report, while rGO impeded the reduction of Ag⁺, resulting in the smaller size and lower density of the formed Ag NPs. As the reaction time increases, the Ag NPs on both single-layer rGO and exposed Si regions continue growing and the size difference of the Ag NPs becomes smaller (Fig. 1D–F). These results demonstrate that the size and density of the deposited Ag NPs can be controlled by the rGO sheets and reaction time. In the following experiments, the fabricated substrate in Fig. 1E was used unless mentioned otherwise.

The adsorption abilities of different kinds of aromatic molecules on rGO were investigated. The rGO-covered Si wafers can be coated with R6G, MV, RB or MB by immersing the wafers into the respective aqueous solutions (400 μM) for 1 h. The AFM images show that the height of rGO increased from 1.1 to 1.8 nm (Fig. S1 in Electronic supplementary information, ESI†), confirming that R6G was successively adsorbed onto rGO sheets, due to the π–π interaction between R6G and rGO. Similarly, MV, RB and MB can also be efficiently adsorbed on rGO sheets (data not shown here).

The as-fabricated Ag NP-decorated rGO film on Si, referred to as Ag NPs-rGO/Si, was used as a SERS substrate for the aforementioned aromatic molecules. The Raman intensities of R6G, MV and RB on bare rGO adsorbed on Si surface, referred to as rGO/Si, are hardly observed, in contrast to the strong Raman signals on the Ag NPs-rGO/Si surface (Fig. 2A–C), indicating the significant role of Ag NPs on the dramatic Raman enhancement. In addition, the strong fluorescence of R6G, MV and RB on Si was observed (Fig. 2A–C). Therefore, the exact enhancement is difficult to be determined. However, the Raman signal of MB on rGO/Si was identified (Fig. 2D), allowing us to determine the enhancement of the fabricated SERS substrate.

The MB molecules were adsorbed on the exposed rGO region and Ag NPs on Ag NPs-rGO/Si, due to the π–π interaction and covalent bonding, respectively. Based on the Raman band of MB at 1625 cm⁻¹, the Raman intensity increases 350 times on the Ag NPs-rGO/Si substrate compared to that on rGO/Si (Fig. 2D), confirming the significant role of Ag NPs on the Raman enhancement of the fabricated SERS substrate. Similarly, the Raman signals of the three other molecules (R6G, MV and RB), which do not adsorb efficiently on Ag, are also dramatically enhanced on the Ag NPs-rGO/Si substrates (Fig. 2A–C). These results proved the ability of Ag NPs-rGO/Si to enhance the Raman signal of aromatic molecules, which in general is not adsorbed efficiently on the plasmonic metals.

Furthermore, Raman intensity of the adsorbed molecules varies with the Ag NP size, which is easily controlled by the reaction time when rGO/Si is immersed into a mixed solution of HF and AgNO₃ (Fig. 3). As the size of Ag NPs increases with the reaction time, the gaps between Ag NPs become smaller, leading to stronger coupling between NPs. At the beginning, Raman intensity of R6G increases with the size increase of Ag NPs, due to the stronger coupling between the NPs. The Raman intensity of R6G on Ag NPs-rGO/Si obtained after 30 s reaction is 6.3 times larger than that on Ag NPs-rGO/Si obtained after
10 s reaction. At 30 s-reaction time, although the area of exposed rGO decreases, the stronger coupling between Ag NPs outdoes this drawback and hence the substrate gives larger Raman enhancement. As the reaction time is prolonged, the Raman intensity becomes stable due to the combination effects, i.e. the stronger coupling between Ag NPs and the smaller area of exposed rGO for adsorption of R6G. These results demonstrate the significant role of rGO sheets and Ag NPs, used for the adsorption of aromatic molecules and Raman enhancement, respectively. Besides Ag NPs, Au NPs can also be coated onto single-layer rGO sheets (Fig. 1G) in a similar way, simply by replacement of AgNO₃ with HAuCl₄ in the electroless deposition procedure. These Au NP-decorated rGO sheets can also be used for highly sensitive Raman detection (data not shown here).

Importantly, quantitative detection of R6G, MV, RB and MB can be carried out by using the as-fabricated SERS substrates. The SERS substrates were immersed into aqueous solutions of the aforementioned molecules with different concentrations for 1 h, and subsequently washed with Milli-Q water and dried by N₂. Fig. 4 shows that R6G, MV, RB and MB can be detected on Ag NPs-rGO/Si SERS substrates even at a low concentration. For example, the Raman signal of R6G could be detected at a concentration of 10 nM, but no signal of R6G was observed on rGO/Si even at a concentration of 1 mM. The Raman signals for MV, RB and MB can be detected at concentrations of 10, 1 and 1 nM, respectively, indicating that the as-fabricated SERS substrate can be used to detect molecules with high sensitivity.

The Raman enhancement can be further increased by replacing the flat Si substrate with Si nanostructure, e.g. Si nanowells. The Si nanowells were fabricated based on modification of the previous method. GO sheets were then assembled onto Si nanowells using LB method and subsequently reduced to rGO with hydrazine vapour. The rGO sheets covered the top of Si nanowells (Fig. 5A, B). Based on the band at 1625 cm⁻¹, Raman intensity of adsorbed MB on rGO sheets on Si nanowells increases about 6 times compared to that on rGO/Si (Fig. 5C), demonstrating that Si nanowells can increase the Raman signal of adsorbed molecules, due to the enhanced light absorption, which is consistent with the previous report.

After the rGO-coated Si nanowells were decorated with Ag NPs using the aforementioned method, the Raman signal was further enhanced. The Raman intensities of R6G, MV and RB on Ag NPs-rGO on Si nanowells increased by about 5 times compared to that on Ag NPs-rGO/Si (Fig. 6A–C). As for MB, the Raman enhancement is even higher, ca. 15.9 times (Fig. 6D), since more MB was adsorbed onto Ag NPs via the covalent bonding. These results demonstrate that the Ag NP-coated Si nanowells can significantly enhance the Raman signal of adsorbed molecules, due to the enhanced light absorption, which is similar to that on bare Si nanowells, but a much stronger Raman signal was obtained on the Ag NP-rGO on Si nanowells. Therefore, the Ag NPs-rGO on Si nanowells can serve as a more efficient SERS substrate for the detection of molecules, especially for aromatic molecules. Since previous reports demonstrated that DNA and protein can be efficiently adsorbed onto graphene surface, we believe our Ag NPs-rGO on Si or Si nanostructures will have great potential for detection of DNA or protein.

**Conclusions**

A simple, convenient and efficient method is developed to fabricate Ag or Au NP-decorated rGO sheets on Si substrates by electroless deposition, which exhibit strong adsorption of aromatic molecules and dramatic Raman enhancement, owing to
Preparation of SERS substrates

GO was synthesized from the natural graphite by using the modified Hummers method. The synthesized GO was re-dispersed in a mixed solution of water and methanol (1 : 5), and then assembled on flat Si substrates or Si nanowell substrates using Langmuir–Blodgett (LB) method. Briefly, a 8–12 mL GO solution was spread onto a water surface in the LB trough at a drop rate of 100 μL min⁻¹. After compression of the GO film on the water surface, a freshly Piranha solution-cleaned Si (or Si nanowell) substrate was vertically dipped into the solution and then slowly pulled up (2 mm min⁻¹) to get a single-layer GO film on the Si. The GO sheets on the Si surface were reduced to obtain reduced graphene oxide (rGO) sheets by hydrazine vapor.

The rGO-covered Si substrate was immersed in a mixed aqueous solution of HF (2%) and AgNO₃ (4 mM) for 15 s–5 min to synthesize a layer of Ag nanoparticles (NPs) onto the rGO and exposed Si surface. The size and distance of Ag NPs could be easily tuned by varying the reaction time. The Ag NPs can be replaced with Au NPs by simply replacing AgNO₃ with HAuCl₄ in the reaction mentioned above.

The Si nanowells were fabricated based on modification of previously reported method. Briefly, Ag NPs, deposited by immersing a Si substrate in a mixed aqueous solution of HF (1%) and AgNO₃ (2 mM) for 60 s, were used as catalyst for the subsequent etching of Si in a mixed solution of H₂O₂ (0.6%) and HF (5%) to generate Si nanowells. After the single-layer rGO film was assembled onto the Si nanowell substrate using the LB method, it was decorated with Ag NPs using the aforementioned electroless deposition method.

The R6G, MV, RB and MB were adsorbed onto the as-fabricated SERS substrates by immersing the 10 mm × 6 mm SERS substrates in 1 mL of the respective aqueous solutions (400 μM) for 1 h. The substrates were then thoroughly washed with Milli-Q water and subsequently dried with N₂. The bulky samples of R6G, MV, RB and MB powder on Si were measured by Raman spectroscopy and used for control experiments.

Characterization of SERS substrates

Scanning electron microscopy (SEM) was performed using a JEOL JSM-6340F field-emission scanning electron micro-analyzer at an accelerating voltage of 5 kV. AFM images were obtained by using Dimension 3100 (Veeco, Santa Barbara, CA, USA) in tapping mode with a Si tip (Tap300-Al, Budget Sensor, spring constant: 42 N m⁻¹, resonant frequency: 320 kHz) under ambient conditions. The Raman detection was carried out on a WITec CRM200 confocal Raman microscopy system with excitation of 633 nm and an air-cooled charge coupled device (CCD) as the detector (WITec Instruments Corp, Germany). The Raman band of a silicon wafer at 520 cm⁻¹ was used as a reference to calibrate the spectrometer.

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Notes and references
